

Electromagnetics:

**Electromagnetic Field Theory** 

# Multi-Segment Transmission Line Devices

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## Lecture Outline

- Quarter-Wave Transformer
- Impedance Matching
- Stubs
- Scattering Parameters

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# Quarter-Wave Transformer

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#### Quarter-Wave Transformer (1 of 2)

A quarter-wave transformer is a section of line that is a  $\lambda/4$  long.

When the length of the line is  $\lambda$  /4, then we have

$$\beta \ell = \frac{2\pi}{\lambda} \cdot \frac{\lambda}{4} = \frac{\pi}{2}$$
 This means the signal accumulates 90° of phase. When told a TL is  $\lambda/4$ , usually no other information is needed.

When this is the case, our impedance transformation equation reduces to

$$\begin{split} Z_{\text{in}}\left(-\ell\right) &= Z_0 \frac{Z_L + jZ_0 \tan\left(\beta\ell\right)}{Z_0 + jZ_L \tan\left(\beta\ell\right)} = Z_0 \frac{Z_L + jZ_0 \tan\left(\pi/2\right)}{Z_0 + jZ_L \tan\left(\pi/2\right)} \\ &= Z_0 \frac{Z_L + jZ_0 \cdot \infty}{Z_0 + jZ_L \cdot \infty} & \tan(\pi/2) = \infty. \\ &= ? \end{split}$$

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#### Quarter-Wave Transformer (2 of 2)

Since both the numerator and denominator are  $\infty$ , we must apply L'Hopital's rule.

$$\lim_{x \to x_0} \frac{f(x)}{g(x)} = \frac{f'(x_0)}{g'(x_0)}$$

Applying this to our impedance transformation equation, we get

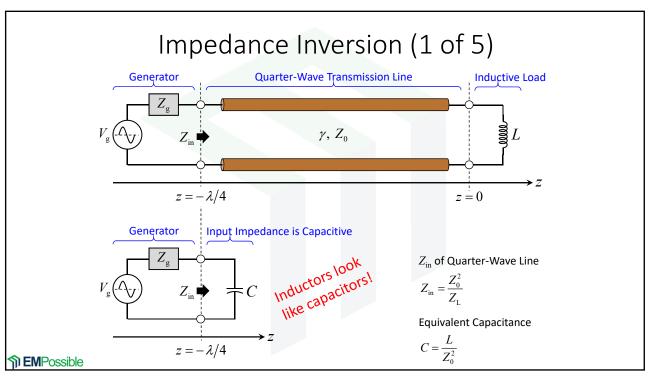
$$Z_{\text{in}}(-\ell) = \lim_{\beta\ell \to \pi/2} Z_0 \frac{Z_{\text{L}} + jZ_0 \tan(\beta\ell)}{Z_0 + jZ_{\text{L}} \tan(\beta\ell)} = Z_0 \frac{jZ_0 \sec^2(\beta\ell)}{jZ_{\text{L}} \sec^2(\beta\ell)} = \frac{Z_0^2}{Z_{\text{L}}}$$

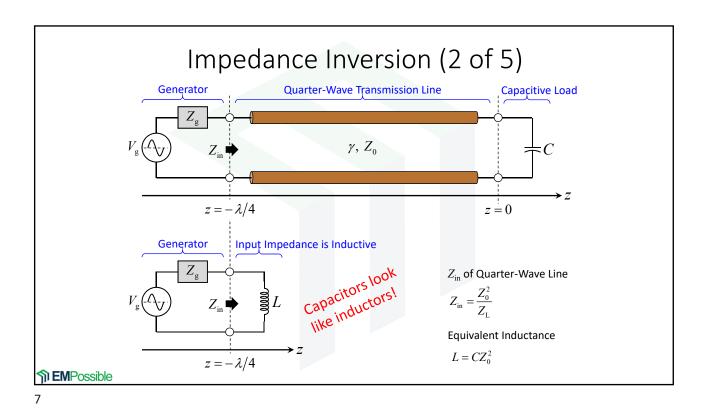
The final equation shows that the load impedance  $Z_{\rm L}$  gets completely inverted. The input impedance becomes the input admittance.

$$Z_{\rm in} \left( -\frac{\lambda}{4} \right) = \frac{Z_0^2}{Z_{\rm L}}$$

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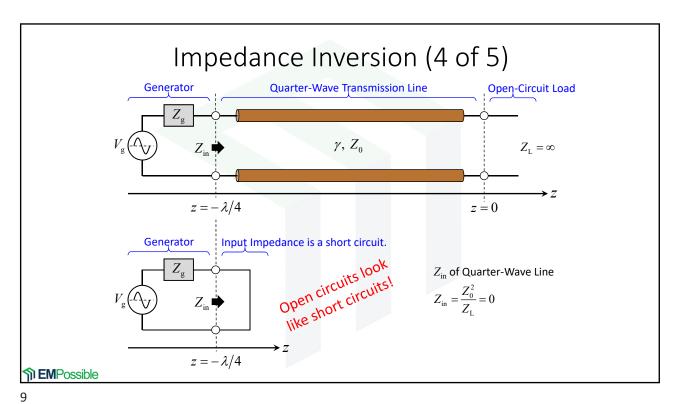


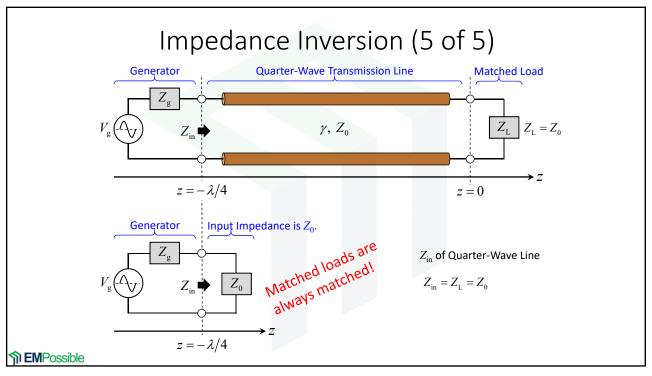
Impedance Inversion (3 of 5)

Generator

Quarter-Wave Transmission Line  $z = -\lambda/4$ Short-Circuit Load z = 0Quarter-Wave Transmission Line z = 0  $z = -\lambda/4$ Short-Circuit Load z = 0 z = 0Generator

Input Impedance is an open circuit. z = 0Short-Circuits look z = 0 z = 0 z = 0 z = 0 z = 0 z = 0 z = 0Short-Circuits look z = 0 z = 0 z = 0 z = 0 z = 0Short-Circuits look z = 0 z = 0Short-Circuits look z = 0 z = 0Short-Circuits look z = 0Short-Circuits look z = 0Short-Circuits look z = 0Short-Circuits look z = 0



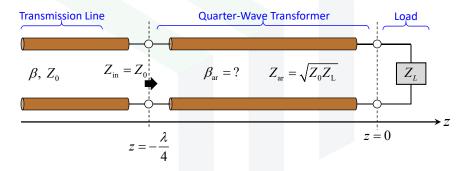


# Impedance Matching

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## Impedance Matching

Similar to the anti-reflection layer for waves, we can match a transmission line to a load impedance by inserting a quarter-wave section of a second transmission line.



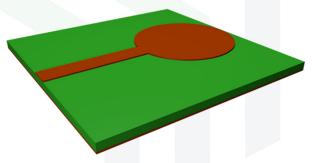
We must perform an electromagnetic analysis of the transmission line to determine  $\beta_{\rm ar}$ 

$$\beta_{\rm ar} \approx \omega \sqrt{\mu_{\rm r} \varepsilon_{\rm r}}$$
  $\ell = \frac{\lambda}{4} = \frac{\pi}{2\beta_{\rm ar}}$ 

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### Example (1 of 3)

A 50  $\Omega$  microstrip line on FR-4 ( $\varepsilon_{\rm r}$  = 4.4) operates at 2.4 GHz and is connected to patch antenna which has a 120  $\Omega$  input impedance. How much power is reflected? How can the circuit be improved?



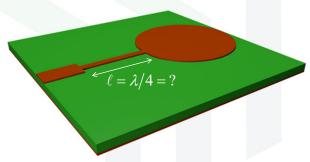
Reflected Power: 
$$\left|\Gamma_{\rm L}\right|^2 = \left|\frac{Z_{\rm L} - Z_{\rm 0}}{Z_{\rm L} - Z_{\rm 0}}\right|^2 = \left|\frac{\left(120~\Omega\right) - \left(50~\Omega\right)}{\left(120~\Omega\right) + \left(50~\Omega\right)}\right|^2 = \left|0.4118\right|^2 = 17\%$$

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### Example (2 of 3)

A 50  $\Omega$  microstrip line on FR-4 ( $\varepsilon_{\rm r}$  = 4.4) operates at 2.4 GHz and is connected to patch antenna which has a 120  $\Omega$  input impedance. How much power is reflected? How can the circuit be improved?



Design:  $Z_{ar} = \sqrt{Z_L Z_0} = \sqrt{(120 \ \Omega)(50 \ \Omega)} = 77.5 \ \Omega$ 

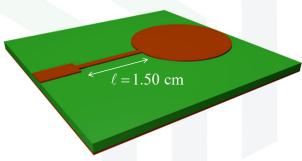
Perform an EM analysis to determine TL dimensions to get 50  $\Omega$ . For TEM mode,

$$\beta = \omega \sqrt{\mu \varepsilon} = \frac{2\pi f}{c_0} \sqrt{\mu_r \varepsilon_r} = \frac{2\pi \left(2.4 \times 10^9 \text{ s}^{-1}\right)}{\left(3.0 \times 10^8 \text{ m/s}\right)} \sqrt{(1.0)(4.4)} = 105.44 \text{ rad/s}$$

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# Example (3 of 3)

A 50  $\Omega$  microstrip line on FR-4 ( $\varepsilon_{\rm r}$  = 4.4) operates at 2.4 GHz and is connected to patch antenna which has a 120  $\Omega$  input impedance. How much power is reflected? How can the circuit be improved?



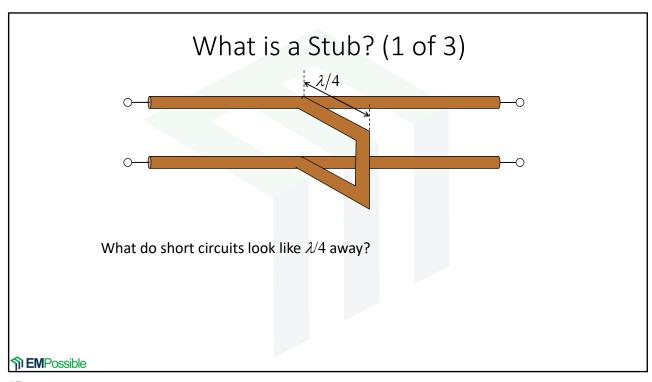
Design: Given  $\beta$ , the length of the line should be

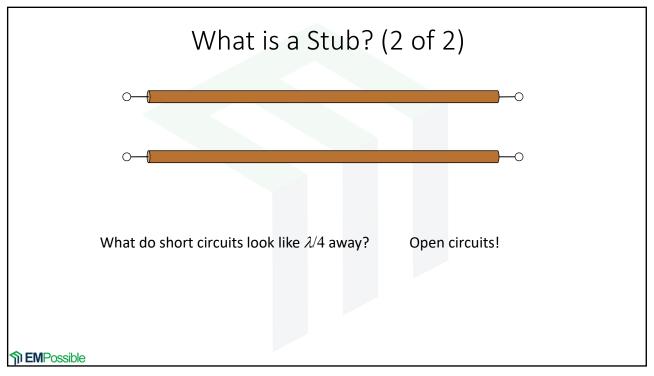
$$\beta_{\text{ar}} \ell = \frac{\pi}{2} \rightarrow \ell = \frac{\pi}{2\beta_{\text{ar}}} = \frac{\pi}{2(105.44 \text{ rad/s})} = 1.4898 \times 10^{-2} \text{ m}$$

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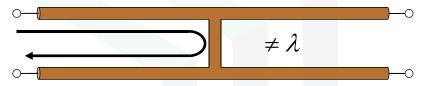
# Stubs



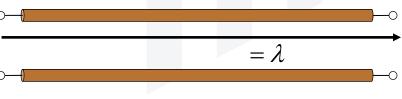


#### The Shorted Stub is a Band Pass Filter

The circuit is actually shorted for all frequencies other than whatever frequency has wavelength  $\lambda$  inside the line. The short circuit blocks all signals.

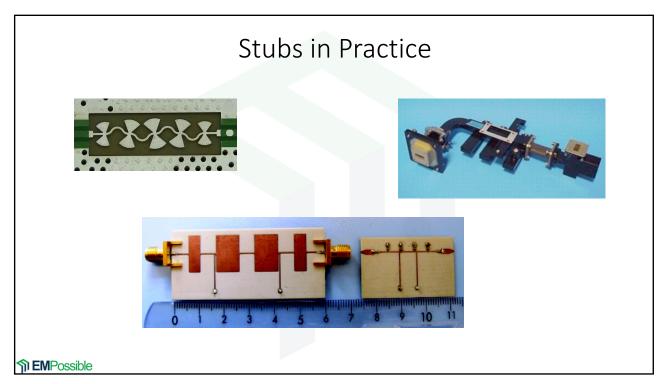


At the frequency with wavelength  $\lambda$ , the circuit is not shorted and signals are allowed to pass.



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# **Scattering Parameters**

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# Definition of a Scattering Matrix

The scattering matrix relates the amplitudes of the input waves to the amplitudes of the output waves.

$$\begin{bmatrix} V_1^- \\ V_2^- \\ \vdots \\ V_N^- \end{bmatrix} = \begin{bmatrix} S_{11} & S_{12} & \cdots & S_{1N} \\ S_{21} & S_{22} & \cdots & S_{2N} \\ \vdots & \vdots & \ddots & \vdots \\ S_{N1} & S_{N2} & & S_{NN} \end{bmatrix} \begin{bmatrix} V_1^+ \\ V_2^+ \\ \vdots \\ V_N^+ \end{bmatrix}$$

$$S_{ij} = \frac{V_i^-}{V_j^+} \Big|_{\text{no other applied voltages}}$$

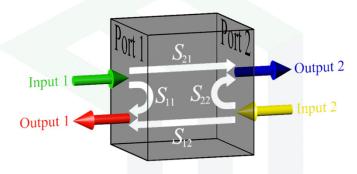
 $V_{2}^{*}, I_{2}^{*}$   $V_{3}^{*}, I_{3}^{*}$   $V_{3}^{*}, I_{3}^{*}$ 

N-Port Network

Any linear system can be reduced to a single scattering matrix that describes how it behaves.

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#### S-Matrix for Two-Port Networks



 $\begin{bmatrix} \text{Output 1} \\ \text{Output 2} \end{bmatrix} = \begin{bmatrix} S_{11} & S_{12} \\ S_{21} & S_{22} \end{bmatrix} \begin{bmatrix} \text{Input 1} \\ \text{Input 2} \end{bmatrix}$ 

 $S_{11}$  is synonymous with reflection coefficient.  $S_{21}$  is synonymous with transmission coefficient.

Very often, engineers will say "S-1-1" instead of saying "reflection," and say "S-2-1" instead of saying transmission.

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### Combining S-Matrices

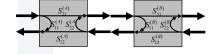
Suppose there are two circuits, A and B, described by scattering matrices that placed in series. What is the scattering matrix of the combined network?

The answer is NOT matrix multiplication!!!

$$\begin{bmatrix} S_{11}^{(AB)} & S_{12}^{(AB)} \\ S_{21}^{(AB)} & S_{22}^{(AB)} \end{bmatrix} \neq \begin{bmatrix} S_{11}^{(A)} & S_{12}^{(A)} \\ S_{21}^{(A)} & S_{22}^{(A)} \end{bmatrix} \begin{bmatrix} S_{11}^{(B)} & S_{12}^{(B)} \\ S_{21}^{(B)} & S_{22}^{(B)} \end{bmatrix}$$

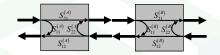
Instead, it is a Redheffer star product.

$$\begin{bmatrix} S_{11}^{(AB)} & S_{12}^{(AB)} \\ S_{21}^{(AB)} & S_{22}^{(AB)} \end{bmatrix} = \begin{bmatrix} S_{11}^{(A)} & S_{12}^{(A)} \\ S_{21}^{(A)} & S_{22}^{(A)} \end{bmatrix} \otimes \begin{bmatrix} S_{11}^{(B)} & S_{12}^{(B)} \\ S_{21}^{(B)} & S_{22}^{(B)} \end{bmatrix}$$



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#### Redheffer Star Product



$$\begin{bmatrix} S_{11}^{(AB)} & S_{12}^{(AB)} \\ S_{21}^{(AB)} & S_{22}^{(AB)} \end{bmatrix} = \begin{bmatrix} S_{11}^{(A)} & S_{12}^{(A)} \\ S_{21}^{(A)} & S_{22}^{(A)} \end{bmatrix} \otimes \begin{bmatrix} S_{11}^{(B)} & S_{12}^{(B)} \\ S_{21}^{(B)} & S_{22}^{(B)} \end{bmatrix}$$

$$\begin{split} S_{11}^{(AB)} &= \frac{S_{11}^{(A)} - S_{11}^{(A)} S_{22}^{(A)} S_{11}^{(B)} + S_{12}^{(A)} S_{21}^{(A)} S_{11}^{(B)}}{1 - S_{22}^{(A)} S_{11}^{(B)}} \\ S_{22}^{(AB)} &= \frac{S_{22}^{(A)} - S_{22}^{(A)} S_{11}^{(B)} S_{22}^{(B)} + S_{22}^{(A)} S_{12}^{(B)} S_{21}^{(B)}}{1 - S_{22}^{(A)} S_{11}^{(B)}} \\ \end{split} \qquad \qquad S_{12}^{(AB)} &= \frac{S_{12}^{(A)} S_{12}^{(B)}}{1 - S_{22}^{(A)} S_{11}^{(B)}} \\ S_{21}^{(AB)} &= \frac{S_{12}^{(A)} S_{12}^{(B)}}{1 - S_{22}^{(A)} S_{11}^{(B)}} \end{split}$$

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